

Technical Data Green Products

Data Sheet N1022, Rev. -

Power Surface Mount Schottky Rectifier (80V/100V, 120Amp)

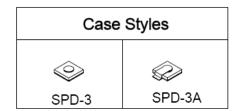
Applications:

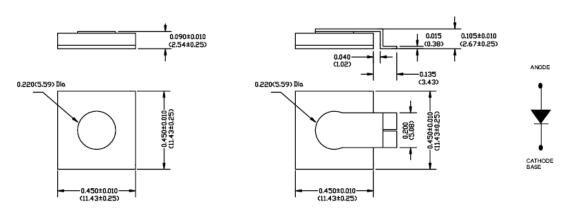
- Switching power supply
- Converters
- Reverse battery protection
- Redundant power subsystems
- Many other high current AC/DC power supplies

Features:

- 175 °C T_J operation
- Low forward voltage drop
- · High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/ Inches





SPD-3A SPD-3A

Suffix "R" Denotes Reversed Polarity

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Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80 (1	123SPC080/A)	V
			100 (1	123SPC100/A)	
Max. Average Forward	$I_{F(AV)}$	50% duty cycle, rectangular wave form		120	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse		1650	А
Non-Repetitive Avalanche Energy(per leg)	E _{AS}	T_J =25 °C, I_{AS} =0.75A, L=40 mH		11.25	mJ
Repetitive Avalanche Current(per leg)	I _{AR}	I_{AS} decaying linearly to 0 in 1 μ sec Frequency limited by T_J max. V_A =1.5 \times V_R		0.75	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V_{F1}	@ 120A, Pulse, T _J = 25 °C	0.87	V
	V_{F2}	@ 120A, Pulse, T _J = 125 °C	0.72	V
Max. Reverse Current (per	I _{R1}	$@V_R = \text{rated } V_R$	2.0	mA
leg) *		T _J = 25 °C		
	I _{R2}	$@V_R = \text{rated } V_R$	48.0	mA
		T _J = 125 °C		
Max. Junction Capacitance	CJ	$@V_R = 5V, T_C = 25 ^{\circ}C$	3000	pF
(per leg)		$f_{SIG} = 1MHz$		
Max. Voltage Rated of	dv/dt	-	10,000	V/μs
Change				

^{*} Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

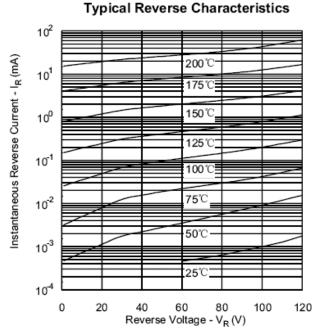
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	°C
Max. Storage Temperature	T_{stg}	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.20	°C/W
Case Style		SPD-3/A		

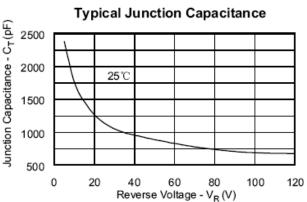
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Typical Forward Characteristics 10² 200°C 10¹ Instantaneous Forward Current - I_F(A) 10⁰ 125℃ 25℃ 10⁻¹ 10⁻² 0.2 0.3 0.4 0.5 0.6 0.7 8.0 Forward Voltage Drop - VF(V)





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